Simulation of the Low Earth Orbital Atomic Oxygen Interaction With Materials by Means of an Oxygen Ion Beam

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SIMULATION OF THE LOW-EARTH ORBITAL ATOMIC OXYGEN INTERACTION

WITH MATERIALS BY MEANS OF AN OXYGEN ION BEAM

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SUMMARY

Atomic oxygen is the predominant species in low-Earth orbit between the altitudes of 180 and 650 km. These highly reactive atoms are a result of photodissociation of diatomic oxygen molecules from solar photons having a wavelength less than or equal to 2430 Å. Spacecraft in low-Earth orbit collide with atomic oxygen in the 3P ground state at impact energies of approximately 4.2 to 4.5 eV. As a consequence, organic materials previously used for high altitude geosynchronous spacecraft are severely oxidized in the low-Earth orbital environment. The evaluation of materials durability to atomic oxygen requires ground simulation of this environment to cost effectively screen materials for durability. Directed broad beam oxygen sources are necessary to evaluate potential spacecraft materials performance before and after exposure to the simulated low-Earth orbital environment. This paper presents a description of a low energy, broad oxygen ion beam source used to simulate the low-Earth orbital atomic oxygen environment. The results of materials interaction with this beam and comparison with actual in-space tests of the same materials will be discussed. Resulting surface morphologies appear to closely replicate those observed in space tests.

INTRODUCTION

Background

The effects of low-Earth orbital (LEO) atomic oxygen interaction with various materials have been studied on space shuttle flights over the past several years (ref. 1). The results of these tests indicate the existence of three major categories of materials evaluated in LEO: (1) materials which readily oxidize, such as most organic polymers; (2) materials which are not readily oxidized or form protective oxide barriers to inhibit further oxidation, such

as most metals; and (3) materials which form volatile oxides at a slow but non-zero rate, such as fluoropolymers. Quantification of the susceptibility of a material to atomic oxygen attack is described as an erosion yield, which is the ratio of the volume or mass of material loss per each incident oxygen atom. The volume erosion yields of over 60 materials evaluated in various low-Earth orbital space experiments are presented in table I.

Many factors may influence the erosion yield of materials, such as impact angle, material temperature, atomic oxygen flux, atomic oxygen fluence, synergistic solar radiation, and atomic oxygen impact energy. Because of the limited amount of in-space testing performed to date, the degree to which these factors influence erosion yield is not well understood. All materials which form volatile oxides upon atomic oxygen bombardment have been found to develop a microscopic surface texture composed of left-standing fibrils or cones. This texture tends to have an influence on the optical properties of materials, causing a significant increase in diffuse reflectance. Table II delineates the changes in solar absorptance and thermal emittance of materials exposed to low-Earth orbital atomic oxygen.

Knowledge of the long-term durability of materials exposed to low-Earth orbital atomic oxygen is crucial to numerous space missions and experiments, such as those being planned in conjunction with Space Station Freedom. Because of the costs associated with in-space performance characterization of candidate materials, ground-based laboratory facilities which simulate the effects of atomic oxygen interaction with materials in low-Earth orbit are desirable. The low-Earth orbital atomic oxygen environment is particularly difficult to simulate because oxygen is essentially in the 3P ground state with mean energies between 4.2 and 4.5 eV. It is very difficult to obtain neutral atomic species at energies which are high compared to convenient thermal energies and low compared to convenient electrostatic energies. As a result, it has been difficult to construct reliable, energetic neutral atom, broad beam facilities with adequate flux to enable accelerated testing of materials. Figure 1 depicts many of the current processes used to simulate the effects of low-Earth orbital atomic oxygen attack on materials. Figure 2 is a flux energy domain plot for 32 atomic oxygen test facilities participating in the NASA Atomic Oxygen Effects Test Program. This test program is intended to further the understanding of atomic oxygen mechanisms and simulation phenomena through collective information gathered from numerous simulation facilities and space test results (ref. 2). The facility numbers shown in figure 2 correspond to the facility numbers and descriptions listed in table III.

Need for Broad Oxygen Beam Exposure Capability

The least expensive and most convenient technique used for evaluating the susceptibility of materials to atomic oxygen attack involves the use of radio frequency oxygen plasma dischargers, commonly called plasma ashers. As can be seen in figure 2, plasma ashers typically produce atomic oxygen at thermal energies of a fraction of an electronvolt. These devices, which also produce excited state species as well as ions and neutral species, are the most commonly used devices for screening material durability to atomic oxygen. Although the energy and purity of species are not optimal, materials which are oxidized by atomic oxygen in plasma ashers have generally been found to oxidize in low-Earth orbit, and materials which have demonstrated atomic oxygen

durability in plasma ashers have been found to be durable in low-Earth orbit. However, there are complications associated with using erosion yield results from plasma ashers to predict performance in space. The relative ranking of erosion rates of a wide variety of materials from asher data frequently does not prove to be reliable for predicting in-space results.

Some materials of mixed organic and inorganic composition indicate modes of oxidative failure in plasma asher testing which may not occur in space. Figure 3 shows a scanning electron photomicrograph of a graphite-epoxy composite sample which was coated with a mica-filled paint and then exposed to atomic oxygen in an RF plasma asher (ref. 3). After exposure, microscopic flakes of mica completely covered the entire exposed surface of the sample, with no paint vehicle remaining. When the flakes were removed, it was quite apparent that atomic oxygen had oxidized the graphite-epoxy surface in spite of the physical appearance of a protective layer. This oxidation may have been produced by RF exitation of gas trapped in voids underneath the protective covering or perhaps by scattering of atomic oxygen which impacted the protective surface from all directions rather than unidirectionally.

Figure 4 shows a photograph of fiberglass-epoxy composite samples before and after exposure to atomic oxygen in an RF plasma asher (ref. 4). When oxidation of the epoxy occurs, the friable glass fibers free themselves from attachment to the underlying bulk material. This process would be expected to slowly terminate because of the glass fibers eventually shielding the underlying epoxy from atomic oxygen attack. However, as can be seen in figure 5, although the rate of mass loss is reduced when the fibers are exposed at an equivalent fluence based on Kapton of approximately $2x10^{21}$ atoms/cm², no further evidence of self-shielding or protection occurs, and the mass loss per unit area continues without any reduction in rate. Somehow, in the RF plasma asher, atomic oxygen is presenting itself to the underlying epoxy without increasing obstruction from the overlying glass fiber layer. In space, the directed atomic oxygen would be expected to gradually be prevented from attacking the underlying epoxy. This may not occur in RF plasma ashers if exitation of the voids between the glass fibers occurs such that exposed glass fibers do not contribute to the protection of the underlying epoxy.

Many high performance materials being considered for use in the low-Earth orbital environment, such as graphite-epoxy or polyimide Kapton, will require atomic oxygen protective coatings. The functional life of these protective coatings depends, to a large degree, upon atomic oxygen interaction at sites of defects in the coatings. In space, atomic oxygen will attack the oxidizable organic material beneath a defect, but the degree of undercutting may be substantially reduced from that obtained in RF plasma ashers because of higher energy and more directed arrival, as illustrated in figure 6. Later in this paper, it will be shown that atomic oxygen has a higher probability of interacting if it has higher impact energy. The lower energy atomic oxygen in plasma ashers arrives at all angles, inviting undercutting, and has a higher probability of scattering and reduced probability of interacting on first impact, which may contribute to undercutting.

Because protective coatings for organic materials must be evaluated for durability in ground simulation systems, it is essential that directed oxygen beam systems be free from these types of flaws, which may cause one to arrive at incorrect conclusions about the modes of failure and lifetime of materials

in low-Earth orbit. It is also desirable for a directed oxygen beam system to have a beam area of an adequate size to perform optical and mechanical functional performance evaluation of candidate materials (typically several centimeters in diameter).

Ion Versus Neutral Atom Considerations

The low-Earth orbital atomic oxygen simulation technique described in this paper utilizes an oxygen ion beam to simulate the effects of neutral atomic oxygen. An unneutralized ion beam impacting an insulating surface will quickly charge the surface to a high positive potential, thus preventing the arrival of additional ions unless that ion beam is space charge neutralized. The ion beam system described in this paper is space charge neutralized by means of an electron emitting filament. Although the electrons do not microscopically reassociate with each ion, they do maintain space charge neutrality and are available to prevent surface charging of insulators.

When ions impact a surface, an electron image charge is present on that surface as the ion approaches impact. Prior to impact, the high electric fields associated with the ion-electron image pair cause the electron to be extracted from the surface and neutralize the incoming ion (ref. 5). Although the oxygen ion now impacts the surface as a neutral atom, there are two issues which may play a role in the impact chemistry which occurs. The incoming atom may be excited by gaining energy in the neutralization process equal to the ionization energy. Also, since the surface has lost an electron, this local charge may contribute to chemical decomposition processes in some materials.

OXYGEN ION BEAM SYSTEM

Vacuum Facility

The oxygen ion beam system is operated in a vacuum facility which is 71 cm in diameter and 171 cm long. The vacuum facility shown in figure 7 is pumped by a perfluorinated ether (Fomblin) diffusion pump oil and roughing pump oil. Figure 8 shows a schematic of the ion beam vacuum system. The vacuum facility is capable of maintaining a pressure of 10^{-4} torr during ion beam source operation with an input source gas flow of 20 standard cubic centimeters/minute of oxygen.

Ion Source

To obtain an adequate flux of ions at low energies, it was necessary to utilize a gridless (end Hall) ion source (ref. 6). The ion source uses a single thermionic cathode as an electron emitter to ionize oxygen gas molecules. The cathode is a source of electrons for space charge neutralization as well. A plasma is formed in the presence of an axially diverging magnetic field, and O_2^+ and O_2^+ ions are formed and accelerated to the order of tens of electronvolts and allowed to impinge on samples located downstream of the ion source. Figure 9 shows a schematic of the gridless ion source. To maintain acceptable sample temperatures at high ion fluxes, it was found to be necessary to shield radiant energy of the cathode from illuminating samples placed downstream of

the ion source. Use of the cathode filament radiation shield reduces the sample temperature while still allowing exposure of samples up to 10 cm in diameter. This area is large enough to perform thermal emittance, solar absorptance, and mechanical characterization of materials exposed to the directed oxygen beam. Figure 10 shows photographs of the ion source relative to the sample holder plate, which contains a current density probe and a quartz crystal microbalance. The sample holder plate is water cooled to maintain acceptable sample temperatures for heat sensitive polymeric samples. Figure 11 shows the dependence of ion energy as a function of applied discharge voltage in the ion source (ref. 6). The gridless ion source produces a divergent ion beam as can be seen in the current density profiles at various locations downstream shown in figure 12. Each milliamp per square centimeter of oxygen ion beam arrival current density represents between 6.25×10^{15} and 1.25×10^{16} oxygen atoms/square centimeter, depending on the ratio of 0^+ to 0^+_2 in the ion beam.

RESULTS AND DISCUSSION

Current Density

Measured current densities as a function of anode potential, oxygen flow rate, and axial distance downstream of the ion source are shown in figures 13(a), (b), and (c), respectively. As can be seen in figure 13(c), for sample target locations 59 cm downstream of the ion source, ion current densities of 0.16 mA/cm² are typically achieved. This represents an atomic oxygen flux of 1×10^{15} atoms/cm²/sec, assuming the beam is 100 percent 0+; or 2×10^{15} atoms/cm²/sec, assuming the oxygen ion beam is 100 percent 0^+_2 . Although characterization of monatomic to diatomic oxygen ion content is planned at the present time, without this information, the oxygen flux can only be specified to within a factor of 2.

Target Temperatures

Use of a radiation shield downstream of the cathode filament reduced sample temperatures from greater than 204 °C to less than 41 °C at sample to ion source distances of 20 cm, based on readings obtained from temperature sensing indicator strips placed on samples located downstream of the ion source.

Erosion Yields of Materials

The erosion yields of five materials selected for the NASA Atomic Oxygen Effects Test Program were evaluated in this ion beam facility. These materials include Kapton HN polyimide, low oxygen content polyethylene, FEP Teflon, pyrolytic graphite, and highly oriented pyrolytic graphite (ref. 2). Table IV compares the erosion yields of these materials with similar materials tested in space. As can be seen in table IV, erosion yields resulting from the ion beam tests are significantly higher than those observed from in-space testing. This is not surprising, because the energy of the oxygen ions is an order of magnitude higher than the energy of atomic oxygen in low-earth orbit. Figure 14 shows a plot of the erosion yield of polyimide Kapton as a function of oxygen ion or atom energy (ref. 7). A wide range of oxygen ion or atom energies is shown on this plot, including data from the facility described in this paper.

Over a large range of energy, the erosion yield appears to depend on the 0.68 power of the oxygen atom or ion energy (ref. 7). Based on this erosion yield versus energy dependence, the ground laboratory oxygen ion beam data for Kapton HN presented in table IV would be expected to produce an erosion yield of $3x10^{-23}$ cm³ per atom, or a factor of 4.7 higher erosion yield, because the oxygen ions had an energy of 41 eV rather than 4.2 to 4.5 eV, which occurs in low-Earth orbit. It is also interesting to note that, although the erosion yields of polyethylene and graphite also appear to be increased by an order of magnitude as a result of this higher energy, the erosion yield of FEP Teflon was increased by 103. This may be a consequence of the individual materials' erosion yield dependence upon energy; or it may be a result of differences between ground laboratory ion exposure and in-space exposure, such as synergistic UV exposure effects or phenomena associated with the ion beam as opposed to a neutral atom beam. Figure 15 shows a photograph of these five materials before and after ion beam exposure to a fluence of 7×10^{18} to 1.5×10^{19} atoms/cm². Figure 16 shows the typical increase in diffuse reflectance of polyimide Kapton exposed to the oxygen ion beam. Figures 17(a) and (b) show scanning electron photomicrographs of the surface of samples of polyimide Kapton HN and pyrolytic graphite exposed to an oxygen beam at a fluence of $3x10^{19}$ to $6x10^{19}$ and 8×10^{19} to 1.6×10^{20} atoms/cm², respectively. These microscopic surface structures appear similar to those which have been observed in space.

Chemical Reactions versus Physical Sputtering

As the energy of oxygen atoms or ions is increased from the thermal energies of an asher to the high energies of several hundred electronvolt ions, the mechanisms for removal of target materials may change from directed chemical oxidation and volatilization to physical sputtering. Although the sputtering threshold of most materials is of the order of tens of electronvolts, physical sputtering of oxygen does not appear to be a dominant surface recession mechanism until one achieves energies on the order of 100 eV. Figure 18 shows the sputter yield for oxygen ions on nickel as a function of energy (ref. 8). The oxygen ion energy in low-Earth orbital simulation systems must be sufficiently low so that physical sputtering of thin film atomic oxygen protective coatings occurs at a very slow rate. Chemical atomic oxygen attack rather than physical sputtering must be the dominant degradation mechanism to properly assess materials durability in low-Earth orbit.

SUMMARY OF RESULTS

Although numerous materials have been evaluated in space, schemes for protection of materials which might oxidize in space have not been fully demonstrated in space and must be evaluated in ground-based laboratory tests prior to consideration for in-space testing. An oxygen ion beam can be used to simulate the effects of low-Earth orbital atomic oxygen attack on materials. The reactivity of the oxygen ion beam appears to be higher than that observed in space. This may be partially due to the higher energy which contributes to the reactivity. The microscopic surface textures produced by oxygen ion beam simulation appear to closely replicate those observed in space. Use of a gridless ion source in conjunction with a cathode filament radiation shield allows the exposure of heat sensitive polymeric materials without thermal decomposition problems. Samples up to 10 cm in diameter can be exposed, allowing postexposure optical and mechanical characterization of materials to be performed.

The oxygen ion energies appear to be sufficiently low so that chemical reaction and not physical sputtering is the dominant mechanism of material removal.

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TABLE I. - EROSION YIELDS OF VARIOUS MATERIALS EXPOSED TO ATOMIC OXYGEN IN LOW-EARTH ORBIT

ATOMIC OXIGER	I IN LOW-EARTH ORBIT	
Material	Erosion yield, x10 ⁻²⁴ cm ³ /atom	Reference
Aluminum (150 Å) Aluminum-coated Kapton Aluminum-coated Kapton Al ₂ 0 ₃ Al ₂ 0 ₃ (700 Å) on Kapton H	0.0 .01 .1 <.025 <.02	1 2 2 3 4
Apiezon grease 2 mm Aquadag E (graphite in an aqueous binder) Carbon	>.625 1.23	5 6 7, 1, 8, 9
Carbon (various forms) Carbon/Kapton 100XAC37 401-C10 (flat black) Chromium (123 Å)	.9 to 1.7 1.5 .30 Partially eroded	10 11 12 14
Chromium (125 Å) on Kapton H Copper (bulk) Copper (1000 Å) on	0.0 0.0 .007	15, 16 17 15, 16
sapphire Copper (1000 Å) Diamond Electrodag 402 (silver in	.0064 .021 .057	14 17 6
a silicone binder) Electrodag 106 (graphite in an epoxy binder)	1.17	6
Epoxy Fluoropolymers:	1.7	10, 16
FEP Kapton Kapton F Teflon, FEP Teflon, FEP Teflon, TFE Teflon, FEP and TFE	.03 <.05 .037 <.05 <.05 0.0 and 0.2	18 6 5 10 10, 6 15, 19
Teflon, FEP and TFE Teflon Teflon Teflon	.1 .109 .5 .03	15 18 15 15
Teflon Gold (bulk) Gold Graphite epoxy:	<.03 0.0 Appears resistant	9 17 20
1034 C 528/T300 GSFC green HOS-875 (bare and preox) Indium Tin oxide Indium Tin oxide/Kapton	2.1 2.6 0.0 0.0 .002 .01	10 10 1 1, 26 15, 16 2
(aluminized) Iridium film Lead Magnesium Magnesium fluoride on glass	.0007 0.0 0.0 .0007	17 1, 26 1, 26 15, 16
Molybdenum (1000 Å) Molybdenum (1000 Å) Molybdenum Mylar Mylar	.0056 .006 0.0 3.4 2.3	4 15, 16 1, 26 10 15, 19
Mylar Mylar Mylar A Mylar A Mylar A	3.9 1.5 to 3.9 3.7 3.4 3.6	15, 19, 9 15 18 21, 6 6 6
Mylar D Mylar D Mylar with Antiox	3.0 2.9 Heavily attacked	21 22

TABLE I. - Continued.

Material	Erosion yield,	Reference
(100.8)	x10 ⁻²⁴ cm ³ /atom	
Nichrome (100 Å) Nickel film	0.0 0.0	1 17
Nickel	0.0	8, 26
Niobium film	0.0 .026	17, 1 10
Osmium Osmium	Heavily attacked	20
Osmium (bulk)	.314	17
Parylene, 2.5 mm	Eroded away 0.0	22 1, 26
Platinum Platinum	Appears resistant	20
Platinum film	0.0	17
Polybenzimidazole	1.5 6.0	10, 7 8
Polycarbonate Polycarbonate resin	2.9	17
Polyester - 7% Poly-	.6	10
silane/93% Polyimide	Hosvilu sttackod	10 22
Polyester Polyester with Antiox	Heavily attacked Heavily attacked	10, 22 10, 22
Polyester (Pen-2,6)	2.9	23
Polyethylene	3.7	10, 21, 16, 15
Polyethylene	3.3	18, 6
Polyimides:		
BJPIPSX-9 BJPIPSX-9	.28 .071	23 24
BJPIPSX-11	.56	23
BJPIPSX-11	.15	24
BTDA-Benzidene BTDA-DAF	3.08 2.82	23 23
BTDA-DAF	.08	24
BTDA-mm-DDS02	2.29	23
BTDA-mm-MDA	3.12 2.91	23 23
BTDA-pp-DABP BTDA-pp-ODA	3.97	23
I-DAB	1.80	23
Kapton (black) Kapton (TV blanket)	1.4 to 2.2 2.0	15, 12 15
Kapton (TV blanket)	2.04	19
Kapton (OSS - 1	2.55	15
blanket) Kapton (OSS - 1	2.5	15
blanket)		
Kapton H	3.0	10, 15, 19, 4, 6,
		9
Kapton H	2.4	15, 19 15, 18
Kapton H Kapton H	2.7 1.5 to 2.8	15, 16
Kapton H	2.0	18
Kapton H	3.1 .1 and .06	18 2
Kapton (uncoated) ODPA-mm-DABP	3.53	23
PEN-2.6	2.90	23
PMDA-pp-DABP PMDA-pp-MDA	3.82 3.17	23 23, 24
PMDA-pp-ODA	4.66	23
Polymethylmethacrylate	3.1	16 10
7% Polysilane/93% Polyimide	.6	'0
25% Polysiloxane, 75%	.3	10
Polyimide	.3	9
25% Polysiloxane Polystyrene-	1.7	10, 16, 9
Polyimide		
Polysulfone Polyvinylidene fluoride	2.4 0.6	10, 16 9
- i o ry v rity i ruelle i luot lue l	2.5	23

TABLE I. - Concluded.

Material	Erosion yield, x10 ⁻²⁴ cm ³ /atom	Reference
S-13-GLO, white SiO ₂ (650 Å) on Kapton H SiO ₂ (650 Å) with <u>4</u> 4% PTFE	0.0 <.0008 <.0008	12 4 4
SiOx/Kapton (aluminized)	.01	2
Silicones: DC1-2577 DC1-2755-coated Kapton DC1-2775-coated Kapton DC6-1104 Grease 60 mm	.055 .05 <.5 .0515 Intact but oxidized	21 15 15 20 25
RTV-560 RTV-615 (black, conductive)	.443	21 20
RTV-615 (clear) RTV-670 RTV-S695 RTV-3145 T-650-coated Kapton Siloxane polyimide	.0625 0.0 1.48 .128 <.5 .3	5 1 11 1 15 7
(25% Sx) Siloxane polyimide	.6	7
(7% Sx) Silver Tantalum Tedlar Tedlar (clear) Tedlar (clear) Tedlar (white) Tedlar (white TiO ₂ , (1000 Å) Trophet 30 (bare and	10.5 Appears resistant 3.2 1.3 and 3.2 3.2 .4 and .6 .05 .0067 0.0	5 20 10 15 18, 6 15 15 5 1, 26
preox) Tungsten Tungsten carbide YB-71 (ZOT) Z302 (glossy black)	0.0 0.0 0.0 3.9	8, 26 8 7 26

TABLE II. - EFFECT OF LEO ATOMIC OXYGEN ON OPTICAL PROPERTIES OF MATERIALS

Material		ptical prope atomic oxyge	rties due to	Reference
	Solar absorptance	Emittance	Reflectance	
Ag/FEP Al/Al ₂ 0 ₃ AlMgF ₂	0.006 006	0.0 0.0	0.0	I I B
Al ₂ 0 ₃ Al ₂ 0 ₃ /Al(He)	0.0 005	0.0	0.0	E I
Al203/Al(Le) Aluminized FEP Teflon, second surface mirror (0.025 mm thick)	006 .05	0.0 19		0
Al Kapton Al Kapton Aluminized Kapton, second surface mirror, uncoated	.048 062 23	.018 007 59		К К О
(0.052 mm thick) Aluminum (150 Å) Aluminum (chromic acid oxidized)	0.0	0.0 0.0	0.0 0.0	B F
Black, carbon-filled PTEE impregnated fiberglass (0.127 mm thick)	16	05		0
Black Cr on Cr on Mo Black Ir on Mo			a _{.20} 75	N N
Black Rh on Mo (matte) Black Rh on Mo (specular) Bostic 463-14	 .01	0.0	25 50	N N J
Chemglaze A276 (w/modifiers)	.006 to .016	.02		A
Chemglaze A276 (white) Chemglaze Z004 Chemglaze Z302 (glossy, black)	.005 .01 .011	.03 0.0 	039 01	B,C J D
Chromium (123 Å) FEP Teflon with silver	0.0 .006	0.0 0.0	0.0	£
undercoat GE-PD-224 GSFC (green) Indium tin oxide coated	0.0 002 .006	0.0 .004		J L K
Kapton H with aluminized backing ITO ring	.006	.004		к
<pre>ITO (S) Sheldahl, black/ Kapton (sputtered)</pre>	.01	0.0		J
ITO (VD) Sheldahl, black/ Kapton (vacuum deposited)	0.0	0.0		J
Ir foil on Al KAT glass			b051 to .01	N N
Kapton with aluminized backing	.048	.018		К
Kapton H (aluminized) Mo (polished) Nickel	.041 .005 004	0.0 0.0	051 0.0 	N I I
Ni/SiO ₂ Polyurethane A-276 Polyurethane A276 glossy white	.023		.01 .2	Ĺ
Polyurethane A276 with 0.5 to 1 mil 0I650 over- coat	.002		3	L
Rh foil on Al			0.0	N

^aMore reflective as a result of the exposed Mo substrate. bLow absolute reflectance (-0.5 to 1 percent).

TABLE II. - Concluded.

Material		ptical proper atomic oxyger		Reference
	Solar absorptance	Emittance	Reflectance	
S13 - GLO SiO ₂ (650 A on Kapton H) SiO _x ring Silicate MS-74 Silicone (black, conductive)	005 0.0 .039 0.01	0.0 0.0 002 0.0 005	0.0	I E K H,A A
Silicone RTV-602/Z302 Silicone RTV-650+Ti0 ₂ Silicone RTV-670 Silicone S1023 Siloxane coating, RTV 602/ on aluminized Kapton, second surface mirror substrate (0.008 mm	.004 .001 004 022 0.0	01 02 0.0	.001	А В G О
thick coating) (0.052 mm thick Kapton) Ti/"tiodized" alloy Ti/"tiodized" CP Urethane (black,	.042	 .55	c25 d40	N N A
conductive) Urethane inhib A-276 YB-71 Z302 glossy black Z302 with MN41-1104-0	0.0 .004 .043 002	.01 0.0 	-4.3	A I L M
overcoat Z302 with OI 651 overcoat Z302 with OI 650 overcoat Z302 with RTV-602 overcoat Z302 with RTV-670 overcoat Z306 Z306 (flat black) Z853, glossy yellow with MN41-1104-0 overcoat	0.0 001 004 004 .022 .028	0.0	.1	M L L I L
Z853, yellow 401 - C10 flat black	034 .005			L L

^CContrast in different spectra between STS-8 and control. Possible aging effects on controls.

dAging effects similar in STS-8 and control. No exposure effect.

TABLE III. - ATOMIC OXYGEN TEST FACILITIES

	<u>.</u>	<u> </u>		· · · · · · · · · · · · · · · · · · ·
Facility number	Organization	Location	Facility description	Test program participant
1 2	Alabama, University of Auburn University	Huntsville, AL Auburn, AL	Thermal A/O source RF plasma excited N is reacted with NO gas to produce thermal ground state A/O	John Gregory Charles Neely
3 4	Auburn University Boeing Aerospace Co.	Auburn, AL Seattle, WA	RF plasma asher Low frequency RF plasma; samples located downstream from glow	Bruce Tatarchuk Gary Pippin Roger Bourassa
5	Case Western Reserve University	Cleveland, OH	Variable energy ion gun	T.G. Eck Dick Hoffman
6	David Sarnoff Research Center	Princeton, NJ	Single grid, low energy ion source	Bawa Singh
7	General Electric - Space Division	Philadelphia, PA	Single grid ion source with charge exchange	Leo Amore James Lloyd
8	Jet Propulsion Lab	Pasadena, CA	Formation of O ⁻ by dissociative attachment. Electrostatic acceleration of ions to final energy, then photodetachment of electrons from ions with a laser	Ara Chutjian Otto Orient
9	Jet Propulsion Lab	Pasadena, CA	Pulsed laser induced breakdown fol- lowed by expansion through a nozzle	David Brinza Ranty Liang
10	Lockheed Palo Alto Research	Palo Alto, CA	RF plasma asher	Matt McCargo
11	Los Alamos National Laboratory	Los Alamos, NM	Continuous laser heated discharge	Jon B. Cross
12	Martin Marietta Denver Aerospace	Denver, CO	Ion gun; magnet for charge/mass selection; multistage aperture for beam deceleration; deflection	Gary W. Sjolander
13	McDonnell Douglas Astronautics Co.	Huntington Beach, CA	RF plasma system with Faraday cage	Esther H. Lan C.A. Smith
14	NASA - Ames Research Center	Moffett Field, CA	Microwave discharge, multisample chamber	Larry L. Fewell
15	NASA — Ames Research Center	Moffett Field, CA	RF O ₂ plasma; samples downstream from plasma glow	Morton Golub Ted Wydevan
16	NASA – Ames Research Center	Moffett Field, CA	RF plasma with sample downstream from glow; sample is UV shielded	Narcinda R. Lerner
17	NASA — Johnson Space Center	Houston, TX	Flowing afterglow	Steven L. Koontz
18	NASA – Johnson Space Center	Houston, TX	RF plasma asher	Steven L. Koontz
19	NASA — Langley Research Center	Hampton, VA	RP plasma asher	Carmen E. Batten
20	NASA — Langley Research Center	Hampton, VA	Electron stimulated desorption from mesh	R.A. Outlaw
21	NASA — Lewis Research Center	Cleveland, OH	Electron bombardment gridless ion source	Bruce A. Banks Sharon K. Rutledge
22	NASA — Lewis Research Center	Cleveland, OH	RF plasma asher run on air	Bruce A. Banks Sharon K. Rutledge
23	NASA — Lewis Research Center	Cleveland, OH	Dissociation and ionization in tun- able microwave cavity followed by electrostatic acceleration	Dale C. Ferguson
24	NASA – Marshall Space Flight Center	MSFC, AL	Electrostatic acceleration Electron bombardment ion source with electromagnetic charge/mass selec- tion downstream, then deceleration with charge neutralization and deflection of nonneutralized ions	Ralph Carruth Jill Carhorl
25	Nebraska, University of Lincoln	Lincoln, NE	RF plasma asher	John A. Woollam
26	Physical Sciences, Inc.	Andover, MA	Pulsed laser induced breakdown fol- lowed by expansion through a nozzle	George Caledonia Robert Krech

TABLE III. - CONCLUDED.

Facility number	Organization	Location	Facility description	Test program participant
27	Princeton Plasma Physics Laboratory	Princeton, NJ	Neutralization of ions formed in plasma by biased plate	William Langer S.A. Cohen D.M. Manos R.W. Motley
28	Texas, University of	Austin, TX	Ion beam with charge exchange	Dennis Kohl
29	Toronto, University of (Aerospace Institute)	Downsview, Ontario, Canada	Microwave generated plasma. Noble gas carrier transports A/O through skimmer to produce high flux density	Rod. C. Tennyson
30	Vanderbilt University	Nashville, TN	Ion gun. Wein filter for charge state selection; deceleration of ions through system of grids; grazing incidence impact with polished nickel surface to neutralize ions. Electrostatic deflection of non-neutralized ions	Royal Albridge N. Tolk
31	NASA Goodard Space Flight Center	Greenbelt, MD	RF plasma asher	Joe A. Colony Edward L. Sanford John J. Scialdone
32	University of Southampton	Highfield, Southampton, UK	Thermal arc beam facility	John Stark
33	Boeing Aerospace Co.	Seattle, WA	Negative ionization beam	Ray Rempt

TABLE IV. - COMPARISON OF ATOMIC OXYGEN TEST PROGRAM MATERIALS, PROPERTIES, AND EROSION YIELDS
FROM IN-SPACE AND GROUND LABORATORY OXYGEN ION BEAM TESTS

Material	Density,	2	Erosion yields			
	gm/cm²	per area on STS-8 ^a	In-space	tests	Ground lab ion	beam tests ^b
		10 ⁻⁸ gm (cm ² sec)	Absolute yield, 10 ⁻²⁴ cm ³ /atom	Relative to Kapton H	Absolute yield, 10 ⁻²⁴ cm ³ /atom	Relative to Kapton HN
Kapton H or HN Polyethylene FEP Teflon Pyrolytic graphite Highly oriented pyrolytic graphite	1.42 .918 2.15 2.2 2.26	1.01 .715 .0188 .623 .640	3.0 3.3 .037 1.2 1.2	1.0 1.1 .012 .40 .40	23 to 46 23 to 46 39 to 77 5 to 11 4.9 to 9.7	1.0 1.0 1.7 .23 .21

aAssuming an STS-8 flux of 2.36×10^{15} atoms/(cm² sec) over an exposure duration of 41.17 hr to produce a fluence of 3.5×10^{20} atoms/cm², 4.4 to 4.5 eV atoms. bPerformed at an oxygen ion beam energy of 41 eV.

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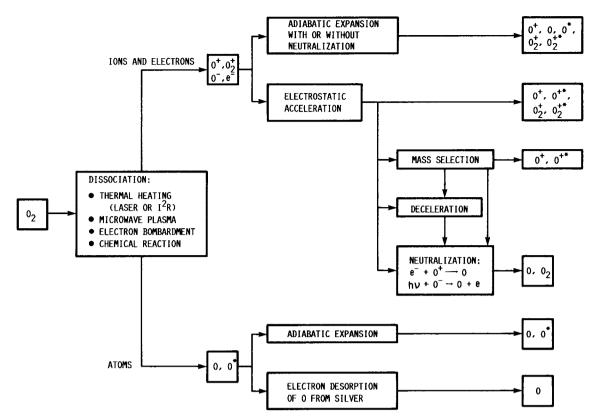


FIGURE 1. - PROCESSES USED FOR SIMULATION OF LOW EARTH ORBITAL ATOMIC OXYGEN.

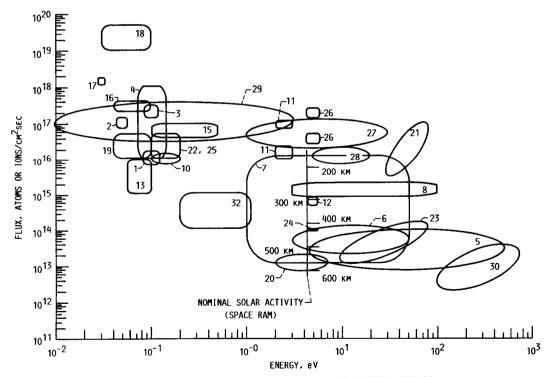


FIGURE 2. - ATOMIC OXYGEN TEST FACILITY FLUX ENERGY DOMAINS.

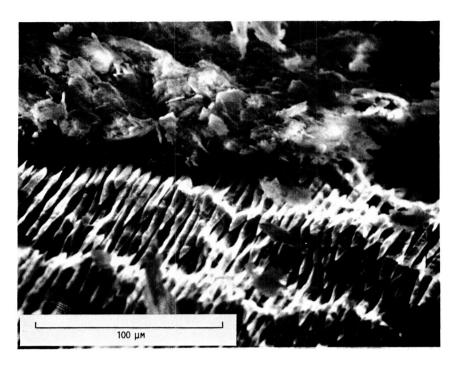


FIGURE 3. - 20.6 MASS PERCENT MICA PAINT ON GRAPHITE EPOXY AFTER 228 HOURS OF EXPOSURE IN AN ASHER. BOTTOM PORTION SHOWS UNDERLYING GRAPHITE EPOXY SUBSTRATE AFTER MICA FLAKES HAVE BEEN REMOVED.

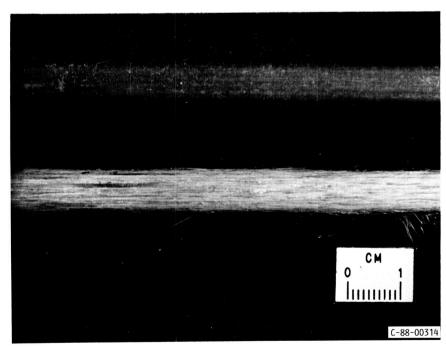


FIGURE 4. - UNEXPOSED (TOP) AND PLASMA EXPOSED 1747 HOURS (BOTTOM) FIBERGLASS-EPOXY.

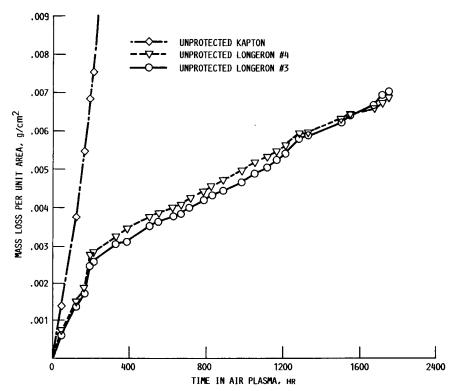


FIGURE 5. - MASS LOSS VERSUS PLASMA EXPOSURE TIME FOR UNPROTECTED FIBERGLASS EPOXY.

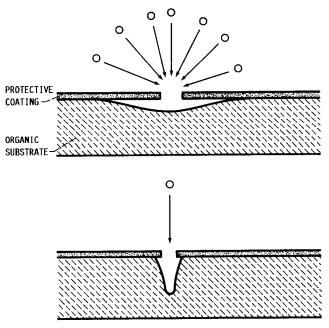


FIGURE 6. - POTENTIAL DIFFERENCE IN ATOMIC OXYGEN UNDERCUTTING BETWEEN RF PLASMA ASHER EXPOSURE (TOP) AND IN-SPACE EXPOSURE (BOTTOM).

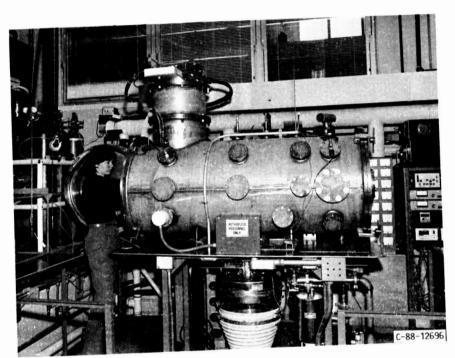


FIGURE 7. - OXYGEN ION BEAM FACILITY.

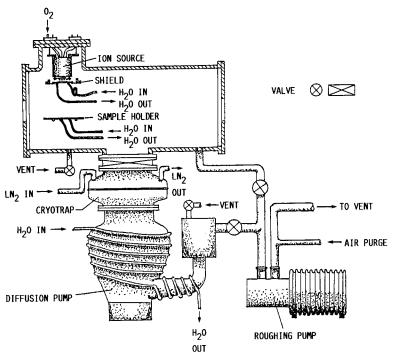


FIGURE 8. - SCHEMATIC OF OXYGEN ION BEAM VACUUM SYSTEM.

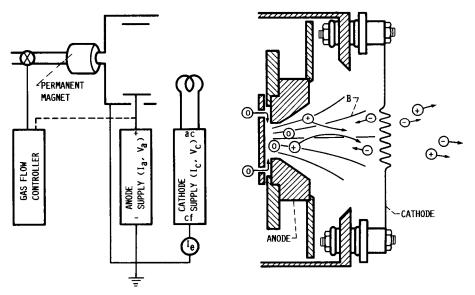
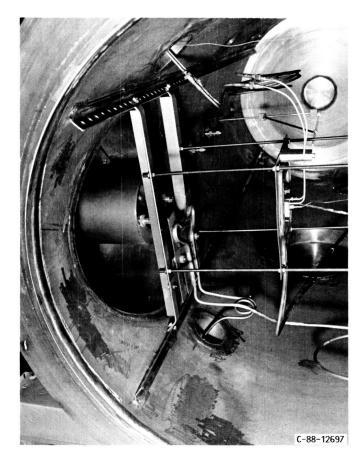


FIGURE 9. - GRIDLESS ION SOURCE.



(A) LOOKING UP TOWARD THE ION SOURCE.



(B) LOOKING DOWN TOWARD THE SAMPLE HOLDER PLATE.

FIGURE 10. - PHOTOGRAPHS OF GRIDLESS ION SOURCE IN RELATION TO THE SAMPLE HOLDER PLATE.

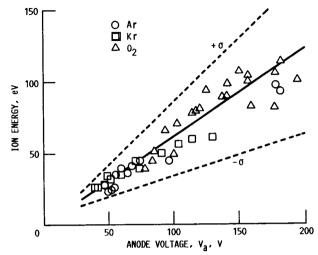


FIGURE 11. - ION ENERGY DEPENDENCE UPON ION SOURCE DISCHARGE VOLTAGE.

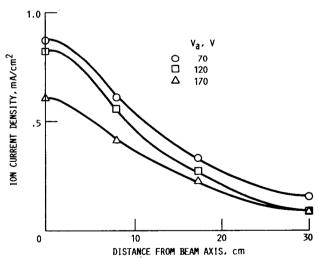
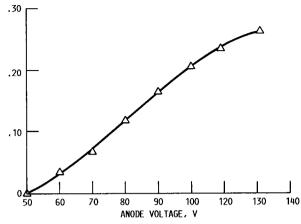
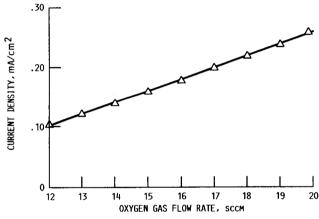


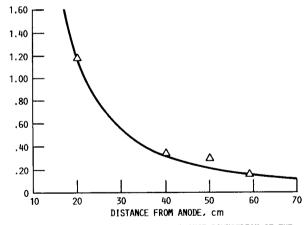
FIGURE 12. - CURRENT DENSITY PROFILES AT AN ANODE CURRENT OF 5 A, AND A SOURCE TARGET DISTANCE OF 30 cm. USING OXYGEN. FLAT TARGET NORMAL TO BEAM AXIS.



(A) AS A FUNCTION OF ANODE VOLTAGE.



(B) AS A FUNCTION OF OXYGEN FLOW RATE.



(C) AS A FUNCTION OF AXIAL DISTANCE DOWNSTREAM OF THE ION SOURCE.

FIGURE 13. - OXYGEN ION CURRENT DENSITY.

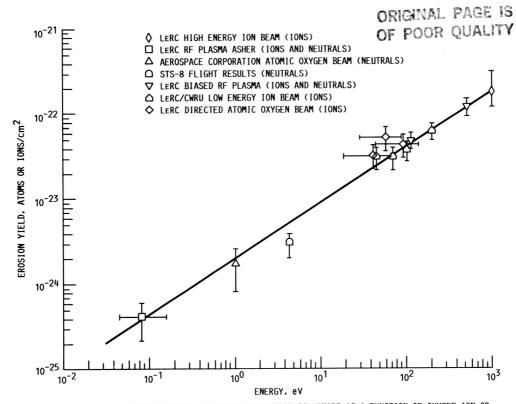


FIGURE 14. - EROSION YIELD DEPENDENCE OF KAPTON POLYIMIDE AS A FUNCTION OF OXYGEN ION OR ATOM ENERGY.

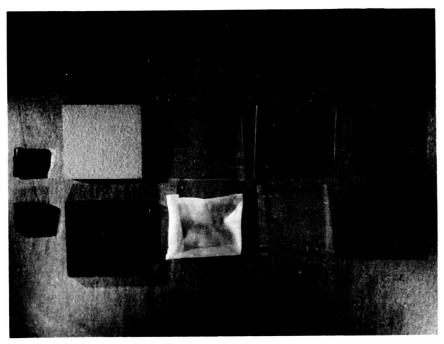


FIGURE 15. - PHOTOGRAPH OF KAPTON HN, POLYETHYLENE, FEP TEFLON, PYROLYTIC GRAPHITE, AND HIGHLY ORIENTED PYROLYTIC GRAPHITE BEFORE AND AFTER ION BEAM EXPOSURE TO A FLUENCE OF 7×10^{18} TO 1.5 \times 10 19 ATOMS/cm².

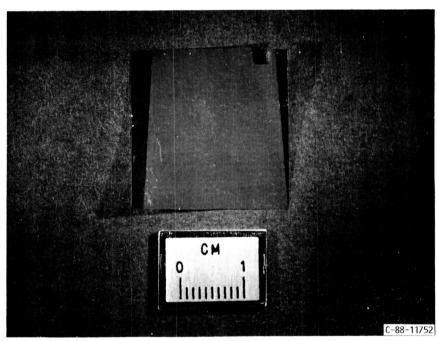
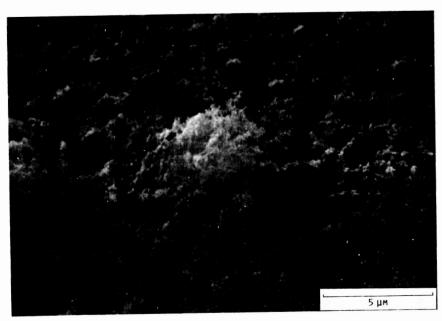
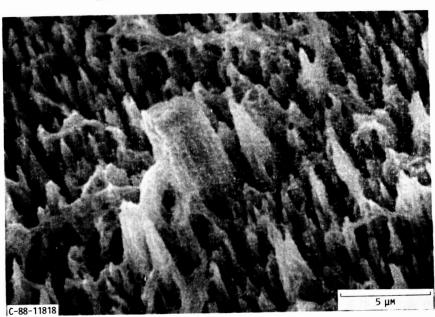


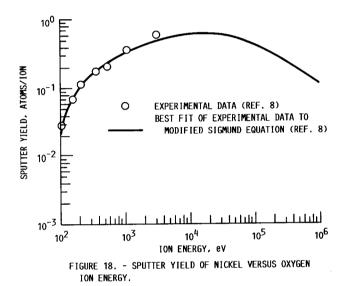
FIGURE 16. – KAPTON HN EXPOSED TO AN OXYGEN ION BEAM TO A FLUENCE OF 3 \times 10 19 To 6 \times 10 19 ATOMS/cm 2 SHOWING CLEAR SPECULAR TRANSMITTANCE ON AREA OF THE SAMPLE PROTECTED FROM ION BEAM EXPOSURE AND DIFFUSE REFLECTANCE ON AREAS OF THE SAMPLE EXPOSED TO THE ION BEAM.



(A) KAPTON HN AFTER 3 x 10^{19} TO 6 x 10^{19} ATOMS/cm 2 .



(B) PRYOLYTIC GRAPHITE AFTER 8 x 10^{19} TO 1.6 x 10^{20} ATOMS/cm 2 . FIGURE 17. - SCANNING ELECTRON PHOTOMICROGRAPHS OF THE SURFACE OF MATERIALS EXPOSED TO AN OXYGEN ION BEAM.



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	Cleveland, Ohio 44135.			Center Group,		
6.	Abstract Atomic oxygen is the predominant spechighly reactive atoms are a result of provided production wavelength less than or equal to 2430 ground state at impact energies of approach approach for high altitude geosynchronous evaluation of materials durability to at effectively screen materials for durability potential spacecraft materials performate environment. This paper presents a detection the low-Earth orbital atomic oxygen experience of the comparision with actual in-space tests appear to closely replicate those observables.	chotodissociation of diatomic oxyger Å. Spacecraft in low-Earth orbit of proximately 4.2 to 4.5 eV. As a correspacecraft are severely oxidized in somic oxygen requires ground simulated before and after exposure to the escription of a low energy, broad oxygenitoring the same materials will be discu	n molecules from solar collide with atomic oxygnequence, organic material the low-Earth orbital eation of this environment ources are necessary to be simulated low-Earth oxygen ion beam sources interaction with this &	50 km. These photons having a gen in the 3P erials previously environment. The ent to cost evaluate orbital used to simulate feam and		
7.	Atomic oxygen is the predominant speninghly reactive atoms are a result of provided pround state at impact energies of approvided pround state at impact energies of approved for high altitude geosynchronous evaluation of materials durability to at effectively screen materials for durability potential spacecraft materials performate environment. This paper presents a detterminant the low-Earth orbital atomic oxygen excomparision with actual in-space tests	chotodissociation of diatomic oxyger Å. Spacecraft in low-Earth orbit of proximately 4.2 to 4.5 eV. As a conspacecraft are severely oxidized in somic oxygen requires ground simulated by Directed broad beam oxygen some before and after exposure to the scription of a low energy, broad oxinvironment. The results of materials of the same materials will be discurved in space tests. 18. Distribution Structure of the same materials will be discurved in space tests.	n molecules from solar collide with atomic oxymsequence, organic material the low-Earth orbital eation of this environment ources are necessary to be simulated low-Earth oxygen ion beam sources interaction with this essed. Resulting surface	50 km. These photons having a gen in the 3P erials previously environment. The ent to cost evaluate orbital used to simulate feam and		